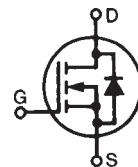


PolarHV™ HiPerFET IXFB 60N80P Power MOSFET

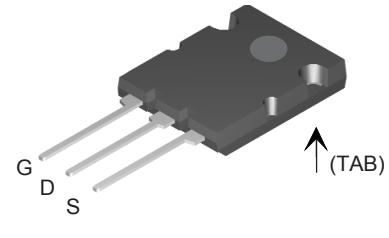
N-Channel Enhancement Mode
Avalanche Rated
Fast Intrinsic Diode

$V_{DSS} = 800$ V
 $I_{D25} = 60$ A
 $R_{DS(on)} \leq 140$ mΩ
 $t_{rr} \leq 250$ ns



Symbol	Test Conditions	Maximum Ratings	
V_{DSS}	$T_J = 25^\circ C$ to $150^\circ C$	800	V
V_{DGR}	$T_J = 25^\circ C$ to $150^\circ C$; $R_{GS} = 1 M\Omega$	800	V
V_{GSS}	Continuous	± 30	V
V_{GSM}	Transient	± 40	V
I_{D25}	$T_c = 25^\circ C$	60	A
I_{DM}	$T_c = 25^\circ C$, pulse width limited by T_{JM}	150	A
I_{AR}	$T_c = 25^\circ C$	30	A
E_{AR}	$T_c = 25^\circ C$	100	mJ
E_{AS}	$T_c = 25^\circ C$	5	J
dv/dt	$I_s \leq I_{DM}$, $di/dt \leq 100$ A/ μ s, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ C$, $R_G = 2 \Omega$	20	V/ns
P_D	$T_c = 25^\circ C$	1250	W
T_J		-55 ... +150	°C
T_{JM}		150	°C
T_{stg}		-55 ... +150	°C
T_L	1.6 mm (0.062 in.) from case for 10 s	300	°C
T_{SOLD}	Plastic body for 10 s	260	°C
F_c	Mounting force	30..120/7.5...2.7	N/lb
Weight		10	g

PLUS264™ (IXFB)



G = Gate D = Drain
S = Source TAB = Drain

Features

- International standard packages
- Fast recovery diode
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
 - easy to drive and to protect

Advantages

- Plus 264™ package for clip or spring
- Space savings
- High power density

Symbol	Test Conditions ($T_J = 25^\circ C$, unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
BV_{DSS}	$V_{GS} = 0 V$, $I_D = 3$ mA	800		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 8$ mA	3.0	5.0	V
I_{GSS}	$V_{GS} = \pm 30$ V _{DC} , $V_{DS} = 0$		± 200	nA
I_{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$		25 3000	μ A
$R_{DS(on)}$	$V_{GS} = 10 V$, $I_D = 0.5 I_{D25}$, Note 1		140	mΩ

Symbol **Test Conditions****Characteristic Values**(T_J = 25°C, unless otherwise specified)

Min. | Typ. | Max.

g_{fs}	V _{DS} = 20 V; I _D = 0.5 I _{D25} , Note 1	35	67	S
C _{iss}		18	nF	
C _{oss}		1200	pF	
C _{rss}		44	pF	
t _{d(on)}		36	ns	
t _r		29	ns	
t _{d(off)}	V _{GS} = 10 V, V _{DS} = 0.5 V _{DSS} , I _D = 0.5 I _{D25}	110	ns	
t _f	R _G = 1 Ω (External)	26	ns	
Q _{g(on)}		250	nC	
Q _{gs}		90	nC	
Q _{gd}	V _{GS} = 10 V, V _{DS} = 0.5 V _{DSS} , I _D = 0.5 I _{D25}	78	nC	
R _{thJC}		0.10 °C/W		
R _{thCS}		0.13	°C/W	

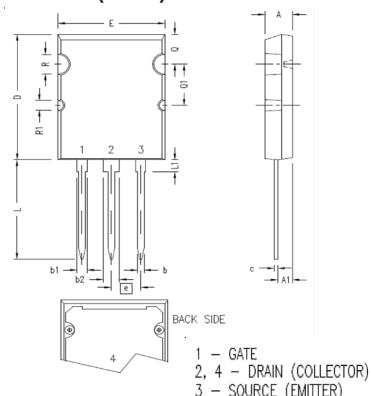
Source-Drain Diode**Characteristic Values**(T_J = 25°C, unless otherwise specified)**Symbol** **Test Conditions**

Min. | Typ. | Max.

I _s	V _{GS} = 0 V		60	A
I _{SM}	Repetitive		150	A
V _{SD}	I _F = I _s , V _{GS} = 0 V, Note 1		1.5	V
t _{rr}	I _F = 25A, -di/dt = 100 A/μs	250	ns	
Q _{RM}	V _R = 100V	0.6	μC	
I _{RM}		6.0	A	

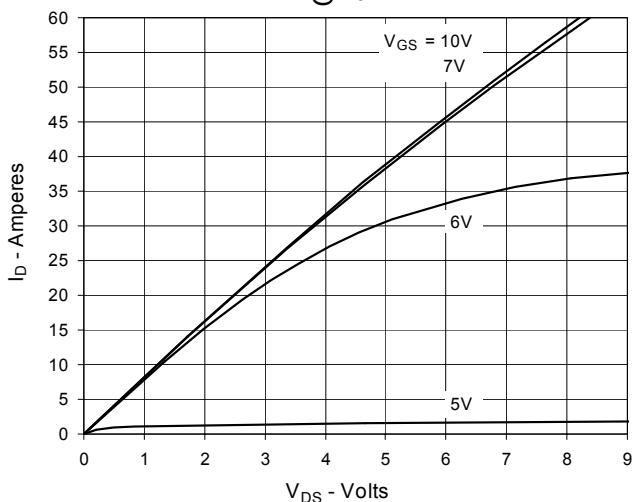
Notes:

1. Pulse test, t ≤ 300 μs, duty cycle d ≤ 2 %

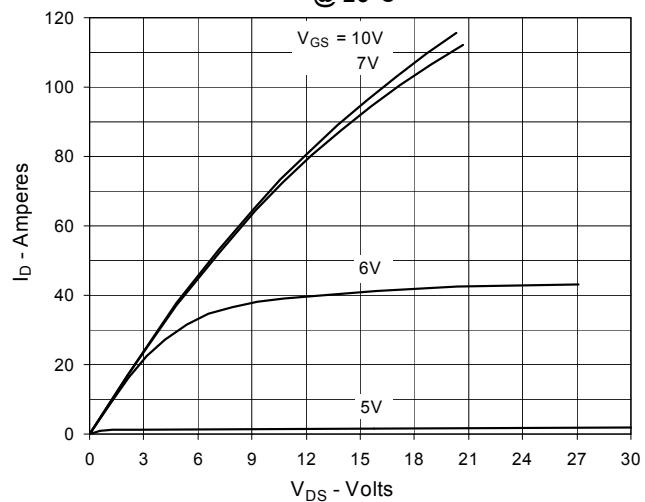
PLUS264™ (IXFB) Outline

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.209	4.70	5.31
A1	.102	.118	2.59	3.00
b	.037	.055	0.94	1.40
b1	.087	.102	2.21	2.59
b2	.110	.126	2.79	3.20
c	.017	.029	0.43	0.74
D	1.007	1.047	25.58	26.59
E	.760	.799	19.30	20.29
e	.215 BSC		5.46 BSC	
L	.779	.842	19.79	21.39
L1	.087	.102	2.21	2.59
Q	.240	.256	6.10	6.50
Q1	.330	.346	8.38	8.79
ØR	.155	.187	3.94	4.75
ØR1	.085	.093	2.16	2.36

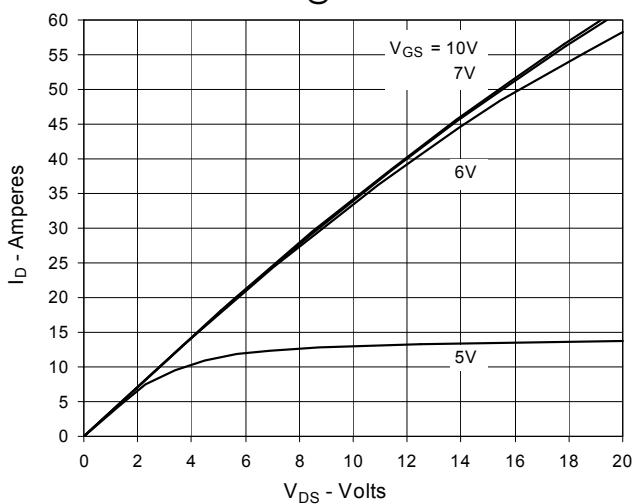
**Fig. 1. Output Characteristics
@ 25°C**



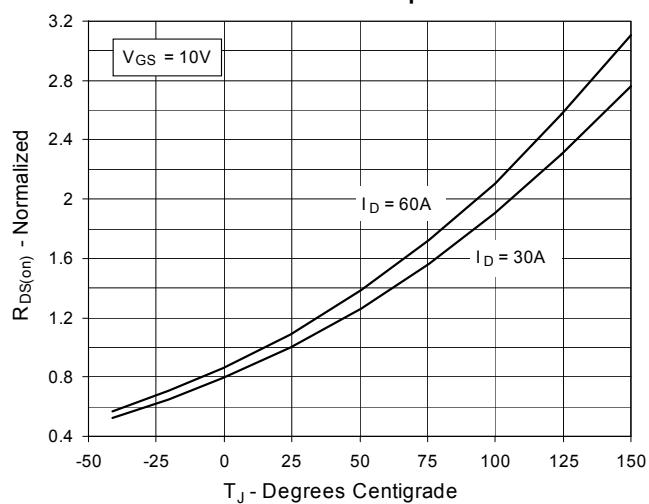
**Fig. 2. Extended Output Characteristics
@ 25°C**



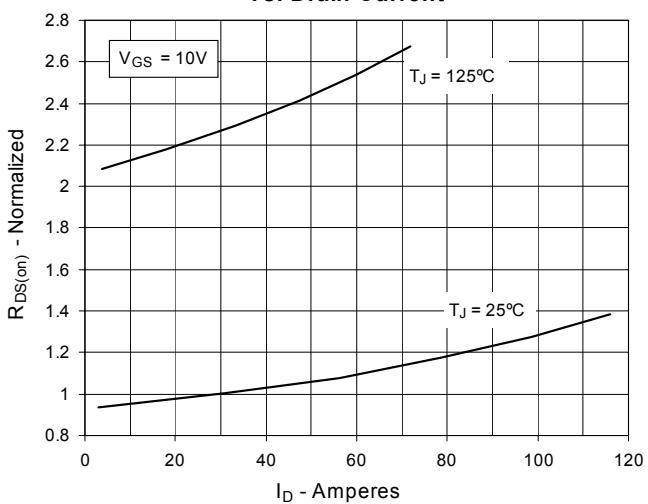
**Fig. 3. Output Characteristics
@ 125°C**



**Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 30A$ Value
vs. Junction Temperature**



**Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 30A$ Value
vs. Drain Current**



**Fig. 6. Maximum Drain Current vs.
Case Temperature**

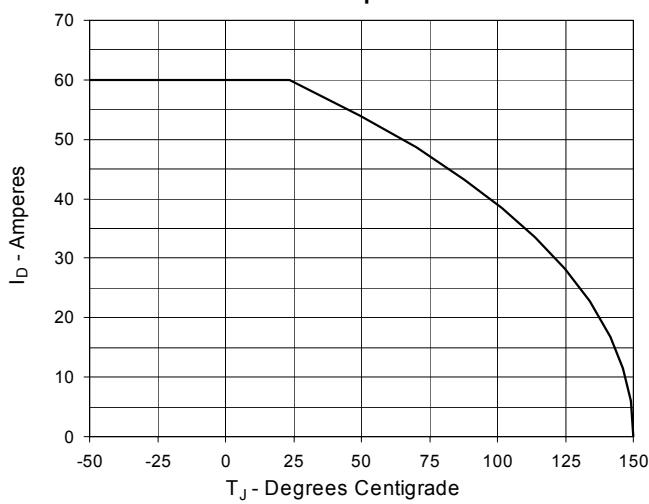
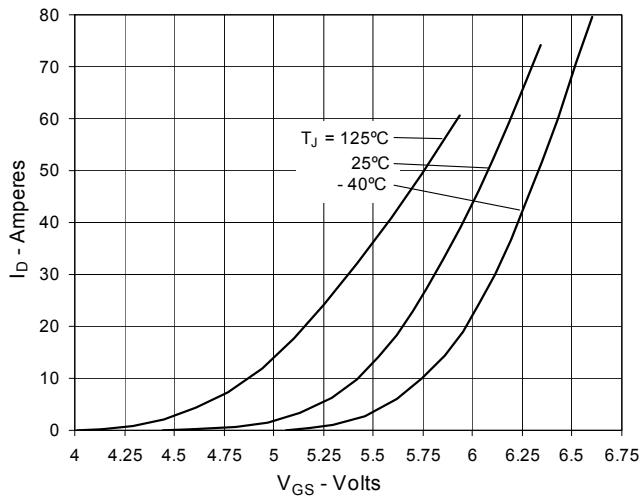
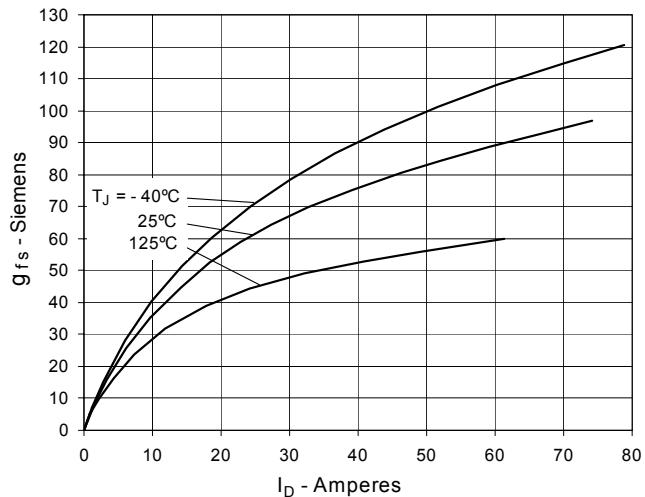
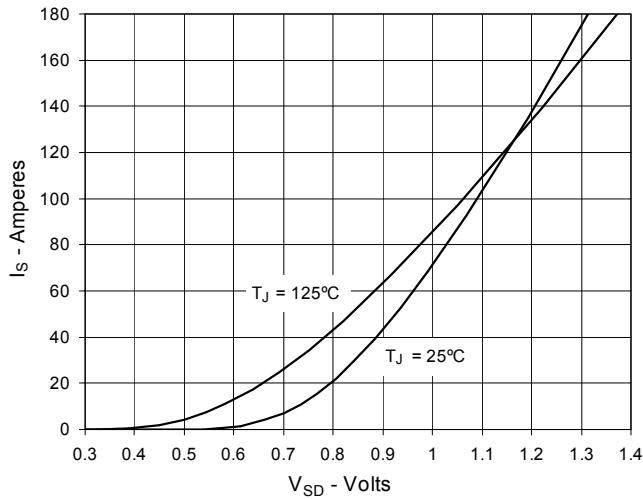
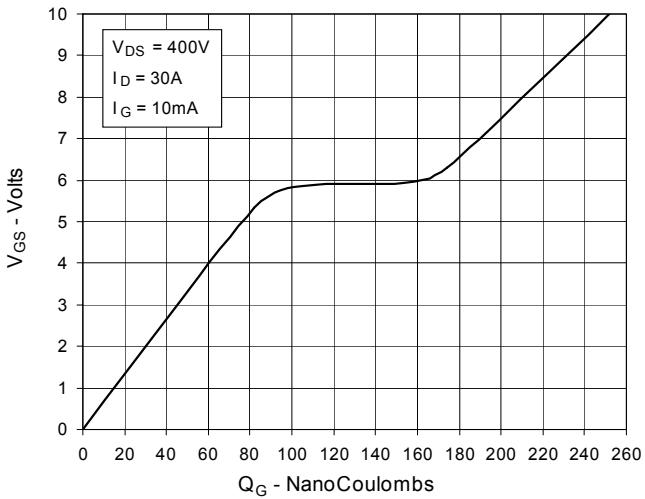
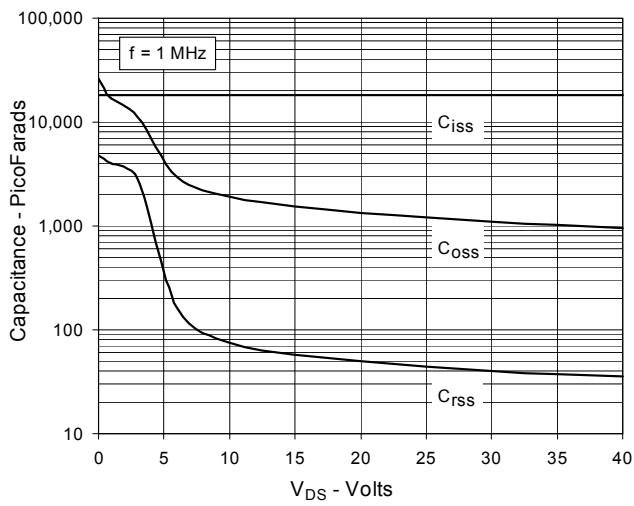
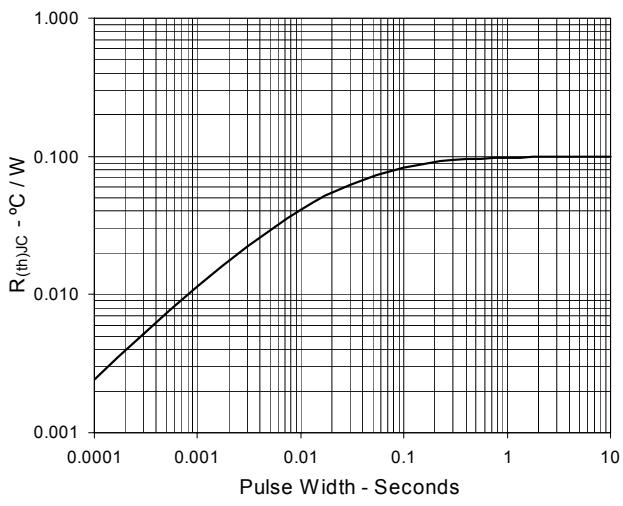


Fig. 7. Input Admittance**Fig. 8. Transconductance****Fig. 9. Forward Voltage Drop of Intrinsic Diode****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Maximum Transient Thermal Resistance**



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